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View Online at https://aerobasegroup.com/nsn/5961-01-346-4156 **Inclosure Material:** Plastic **Overall Length:** 0.405 inches **Terminal Length:** 0.135 inches **Overall Height:** 0.250 inches **Overall Width:** 0.245 inches Lens Transparency: Translucent all light emitting diode **Function For Which Designed:** Visible light emitting **End Application:** 5895-01-163-1168 **Component Name And Quantity:** 4 light emitting diode **Mounting Method: Terminal Semiconductor Material:** Gallium arsenide phosphide all light emitting diode Voltage Rating In Volts Per Characteristic: 5.0 forward voltage, dc all light emitting diode **Current Rating Per Characteristic:** 40.00 milliamperes source cutoff current preset all light emitting diode **Color Tone Produced Per Source:** Red lens all light emitting diode **Luminous Intensity:** 3.0 millicandela all light emitting diode **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Special Features:** All light emitting diode junction pattern arrangement: pn **Terminal Type And Quantity:** 8 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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